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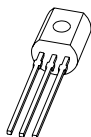
Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China





PBSS9110S

100 V, 1 A PNP low V_{CEsat} (BISS) transistor

Rev. 03 — 22 November 2009

Product data sheet

1. Product profile

1.1 General description

PNP low V_{CEsat} transistor in a SOT54 (SC-43/TO-92) plastic package.

1.2 Features

- SOT54 package
- Low collector-emitter saturation voltage V_{CEsat}
- High collector current capability I_C and I_{CM}
- High efficiency leading to less heat generation

1.3 Applications

- Major application segments:
 - ◆ Automotive 42 V power
 - ◆ Telecom infrastructure
 - ◆ Industrial
- Peripheral driver:
 - ◆ Driver in low supply voltage applications (e.g. lamps and LEDs)
 - ◆ Inductive load driver (e.g. relays, buzzers and motors)
- DC-to-DC converter

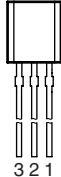
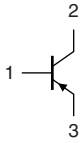
1.4 Quick reference data

Table 1. Quick reference data

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|-------------|---------------------------|------------|-----|-----|------|------------|
| V_{CEO} | collector-emitter voltage | | - | - | -100 | V |
| I_C | collector current (DC) | | - | - | -1 | A |
| I_{CM} | peak collector current | | - | - | -3 | A |
| R_{CEsat} | equivalent on-resistance | | - | - | 320 | m Ω |

2. Pinning information

Table 2. Discrete pinning

| Pin | Description | Simplified outline | Symbol |
|-----|-------------|---|--|
| 1 | base |  |  <i>sym029</i> |
| 2 | collector | | |
| 3 | emitter | | |

3. Ordering information

Table 3. Ordering information

| Type number | Package | | |
|-------------|---------|---|---------|
| | Name | Description | Version |
| PBSS9110S | - | plastic single-ended leaded (through hole) package; 3 leads | SOT54 |

4. Marking

Table 4. Marking

| Type number | Marking code |
|-------------|-----------------------|
| PBSS9110S | S9110S ^[1] |

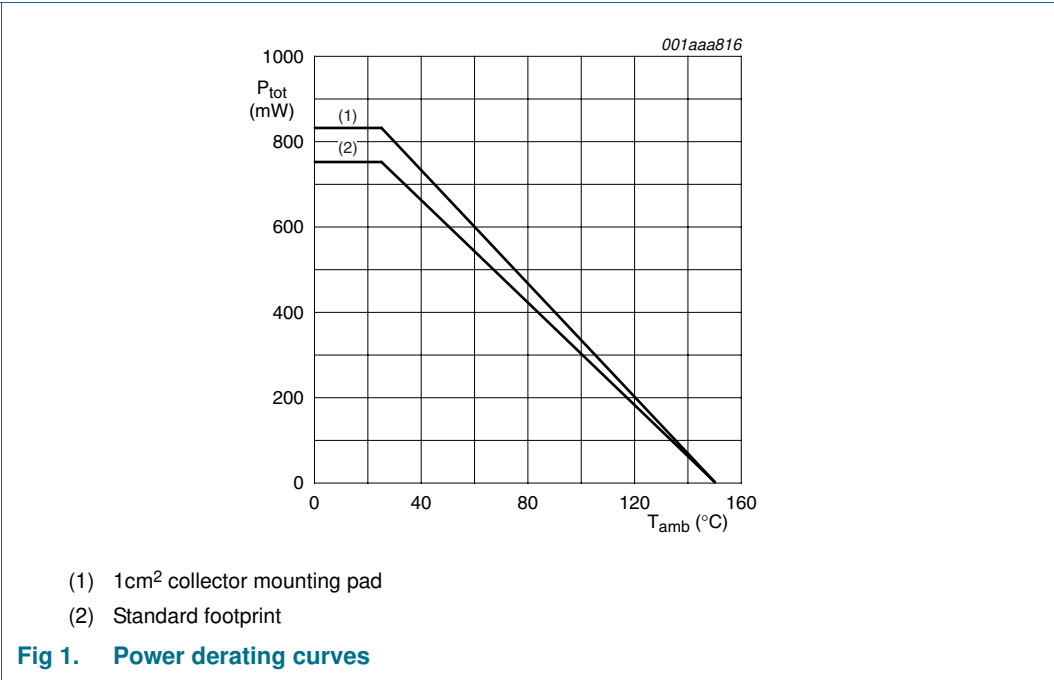
[1] Made in China

5. Limiting values

Table 5. Limiting values
In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|-----------|-------------------------------|---|-----|------|--------------------|
| V_{CBO} | collector-base voltage | open emitter | - | -120 | V |
| V_{CEO} | collector-emitter voltage | open base | - | -100 | V |
| V_{EBO} | emitter-base voltage | open collector | - | -5 | V |
| I_{CM} | peak collector current | $T_{j(max)}$ | - | -3 | A |
| I_C | collector current (DC) | | - | -1 | A |
| I_B | base current (DC) | | - | -0.3 | A |
| P_{tot} | total power dissipation | $T_{amb} \leq 25\text{ }^{\circ}\text{C}$ [1] | - | 830 | mW |
| T_j | junction temperature | | - | 150 | $^{\circ}\text{C}$ |
| T_{amb} | operating ambient temperature | | -65 | +150 | $^{\circ}\text{C}$ |
| T_{stg} | storage temperature | | -65 | +150 | $^{\circ}\text{C}$ |

[1] Device mounted on a FR4 printed-circuit board, single-sided copper, tin-plated, standard footprint.

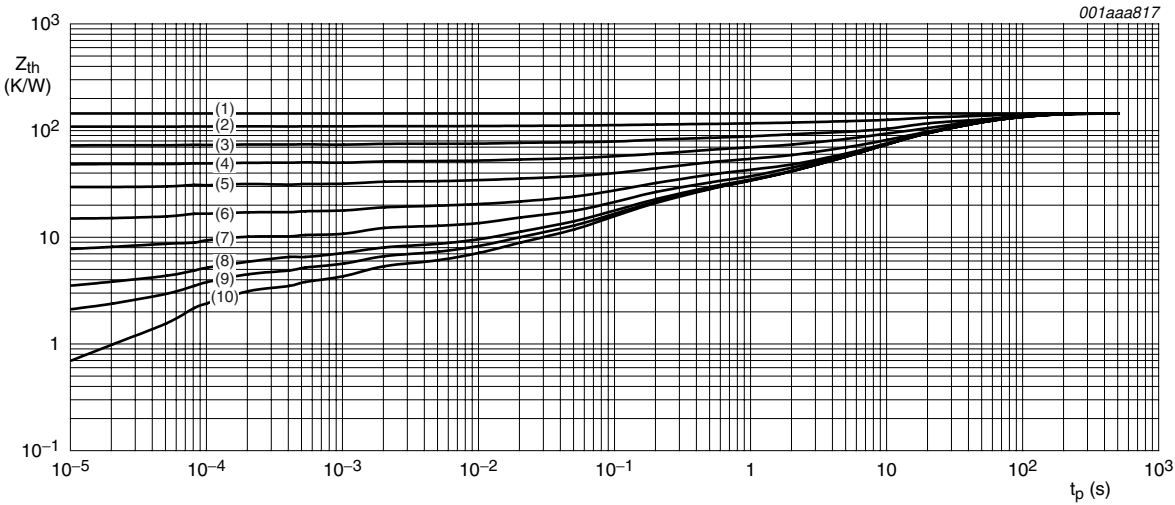


6. Thermal characteristics

Table 6. Thermal characteristics

| Symbol | Parameter | Conditions | Typ | Unit |
|---------------|---|-------------|-----|------|
| $R_{th(j-a)}$ | thermal resistance from junction to ambient | in free air | 150 | K/W |

[1] Device mounted on a FR4 printed-circuit board, single-sided copper, tin-plated, standard footprint.



Mounted on FR4 PCB; standard footprint

- (1) $\delta = 1$
- (2) $\delta = 0.75$
- (3) $\delta = 0.5$
- (4) $\delta = 0.33$
- (5) $\delta = 0.2$
- (6) $\delta = 0.1$
- (7) $\delta = 0.05$
- (8) $\delta = 0.02$
- (9) $\delta = 0.01$
- (10) $\delta = 0$

Fig 2. Transient thermal impedance as a function of pulse time; typical values

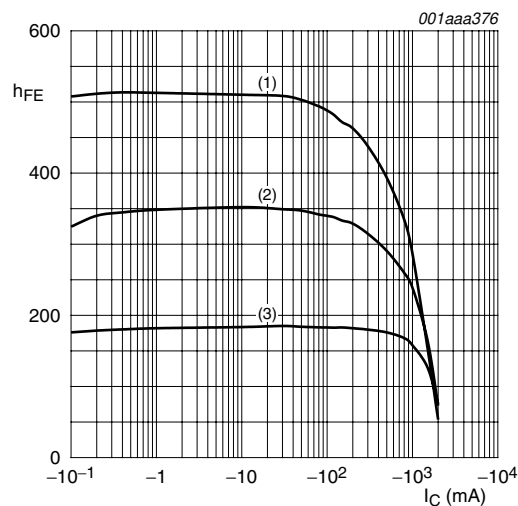
7. Characteristics

Table 7. Characteristics

$T_{amb} = 25\text{ }^{\circ}\text{C}$ unless otherwise specified.

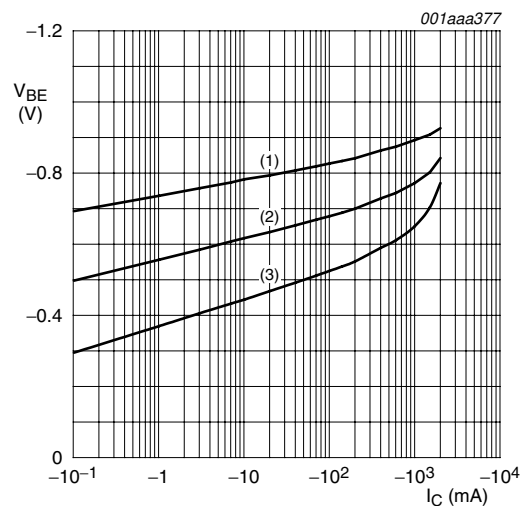
| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|-------------|--------------------------------------|--|-----|-----|------|------------------|
| I_{CBO} | collector-base cut-off current | $V_{CB} = -80\text{ V}; I_E = 0\text{ A}$ | - | - | -100 | nA |
| | | $V_{CB} = -80\text{ V}; I_E = 0\text{ A}; T_j = 150\text{ }^{\circ}\text{C}$ | - | - | -50 | μA |
| I_{CES} | collector-emitter cut-off current | $V_{CE} = -80\text{ V}; V_{BE} = 0\text{ V}$ | - | - | -100 | nA |
| I_{EBO} | emitter-base cut-off current | $V_{EB} = -4\text{ V}; I_C = 0\text{ A}$ | - | - | -100 | nA |
| h_{FE} | DC current gain | $V_{CE} = -5\text{ V}; I_C = -1\text{ mA}$ | 150 | - | - | |
| | | $V_{CE} = -5\text{ V}; I_C = -250\text{ mA}$ | 150 | - | - | |
| | | $V_{CE} = -5\text{ V}; I_C = -0.5\text{ A}$ [1] | 150 | - | 450 | |
| | | $V_{CE} = -5\text{ V}; I_C = -1\text{ A}$ [1] | 125 | - | - | |
| V_{CEsat} | collector-emitter saturation voltage | $I_C = -250\text{ mA}; I_B = -25\text{ mA}$ | - | - | -120 | mV |
| | | $I_C = -500\text{ mA}; I_B = -50\text{ mA}$ | - | - | -180 | mV |
| | | $I_C = -1\text{ A}; I_B = -100\text{ mA}$ | - | - | -320 | mV |
| R_{CEsat} | equivalent on-resistance | $I_C = -1\text{ A}; I_B = -100\text{ mA}$ [1] | - | 170 | 320 | $\text{m}\Omega$ |
| V_{BEsat} | base-emitter saturation voltage | $I_C = -1\text{ A}; I_B = -100\text{ mA}$ | - | - | -1.1 | V |
| V_{BEon} | base-emitter turn-on voltage | $I_C = -1\text{ A}; V_{CE} = -5\text{ V}$ | - | - | -1.0 | V |
| f_T | transition frequency | $I_C = -50\text{ mA}; V_{CE} = -10\text{ V}; f = 100\text{ MHz}$ | 100 | - | - | MHz |
| C_c | collector capacitance | $I_E = I_e = 0\text{ A}; V_{CB} = -10\text{ V}; f = 1\text{ MHz}$ | - | - | 17 | pF |

[1] Pulse test: $t_p \leq 300\text{ }\mu\text{s}$; $\delta \leq 0.02$.



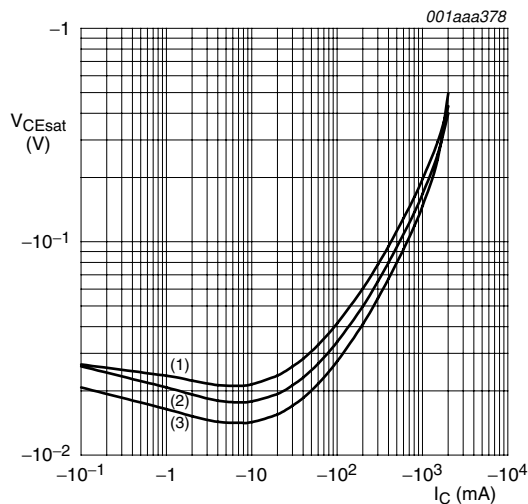
- $V_{CE} = -10$ V
- (1) $T_{amb} = 100$ °C
 - (2) $T_{amb} = 25$ °C
 - (3) $T_{amb} = -55$ °C

Fig 3. DC current gain as a function of collector current; typical values



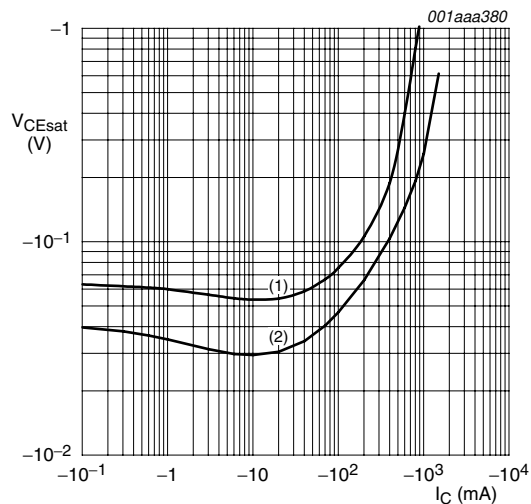
- $V_{CE} = -10$ V
- (1) $T_{amb} = -55$ °C
 - (2) $T_{amb} = 25$ °C
 - (3) $T_{amb} = 100$ °C

Fig 4. Base-emitter voltage as a function of collector current; typical values



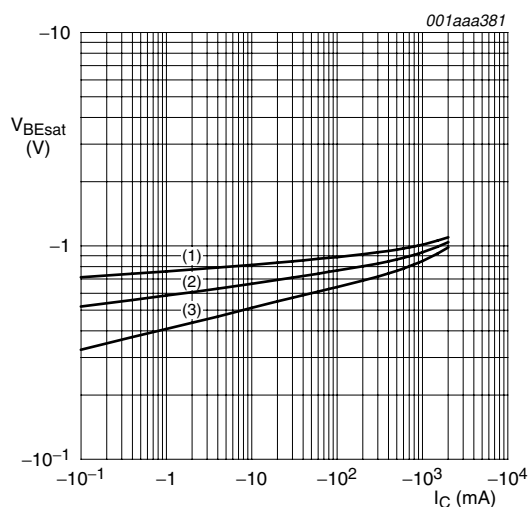
- $I_C/I_B = 10$
- (1) $T_{amb} = 100$ °C
 - (2) $T_{amb} = 25$ °C
 - (3) $T_{amb} = -55$ °C

Fig 5. Collector-emitter saturation voltage as a function of collector current; typical values



- $T_{amb} = 25$ °C
- (1) $I_C/I_B = 50$
 - (2) $I_C/I_B = 20$

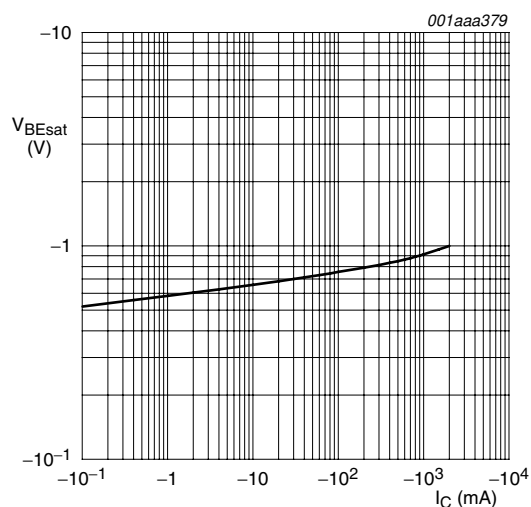
Fig 6. Collector-emitter saturation voltage as a function of collector current; typical values



$$I_C/I_B = 10$$

- (1) $T_{amb} = -55\text{ °C}$
- (2) $T_{amb} = 25\text{ °C}$
- (3) $T_{amb} = 100\text{ °C}$

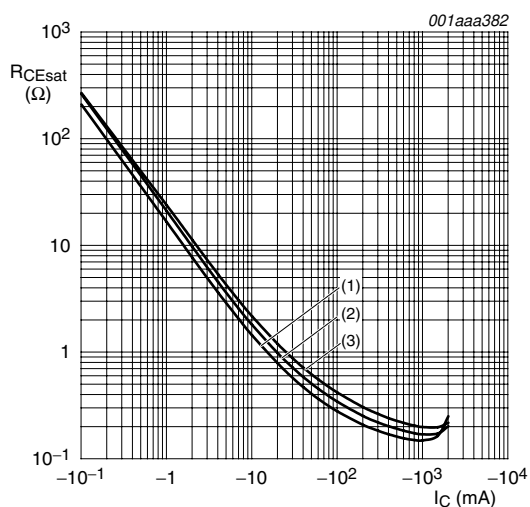
Fig 7. Base-emitter saturation voltage as a function of collector current; typical values



$$I_C/I_B = 20$$

$$T_{amb} = 25\text{ °C}$$

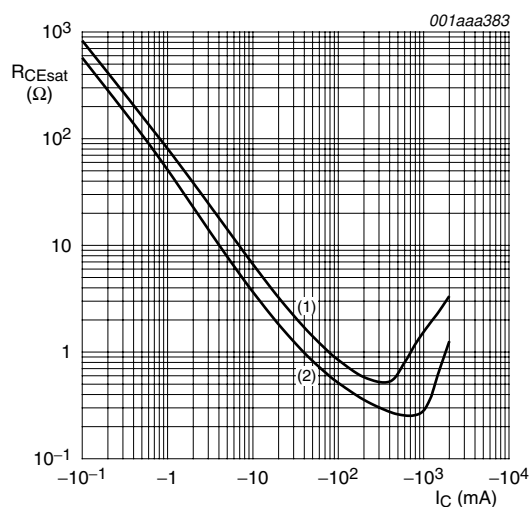
Fig 8. Base-emitter saturation voltage as a function of collector current; typical values



$$I_C/I_B = 10$$

- (1) $T_{amb} = -55\text{ °C}$
- (2) $T_{amb} = 25\text{ °C}$
- (3) $T_{amb} = 100\text{ °C}$

Fig 9. Equivalent on-resistance as a function of collector current; typical values



$$T_{amb} = 25\text{ °C}$$

- (1) $I_C/I_B = 50$
- (2) $I_C/I_B = 20$

Fig 10. Equivalent on-resistance as a function of collector current; typical values

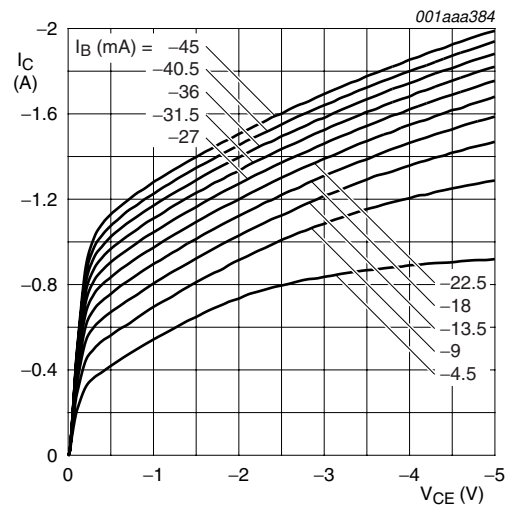


Fig 11. Collector current as a function of collector-emitter voltage; typical values

8. Package outline

Plastic single-ended leaded (through hole) package; 3 leads

SOT54

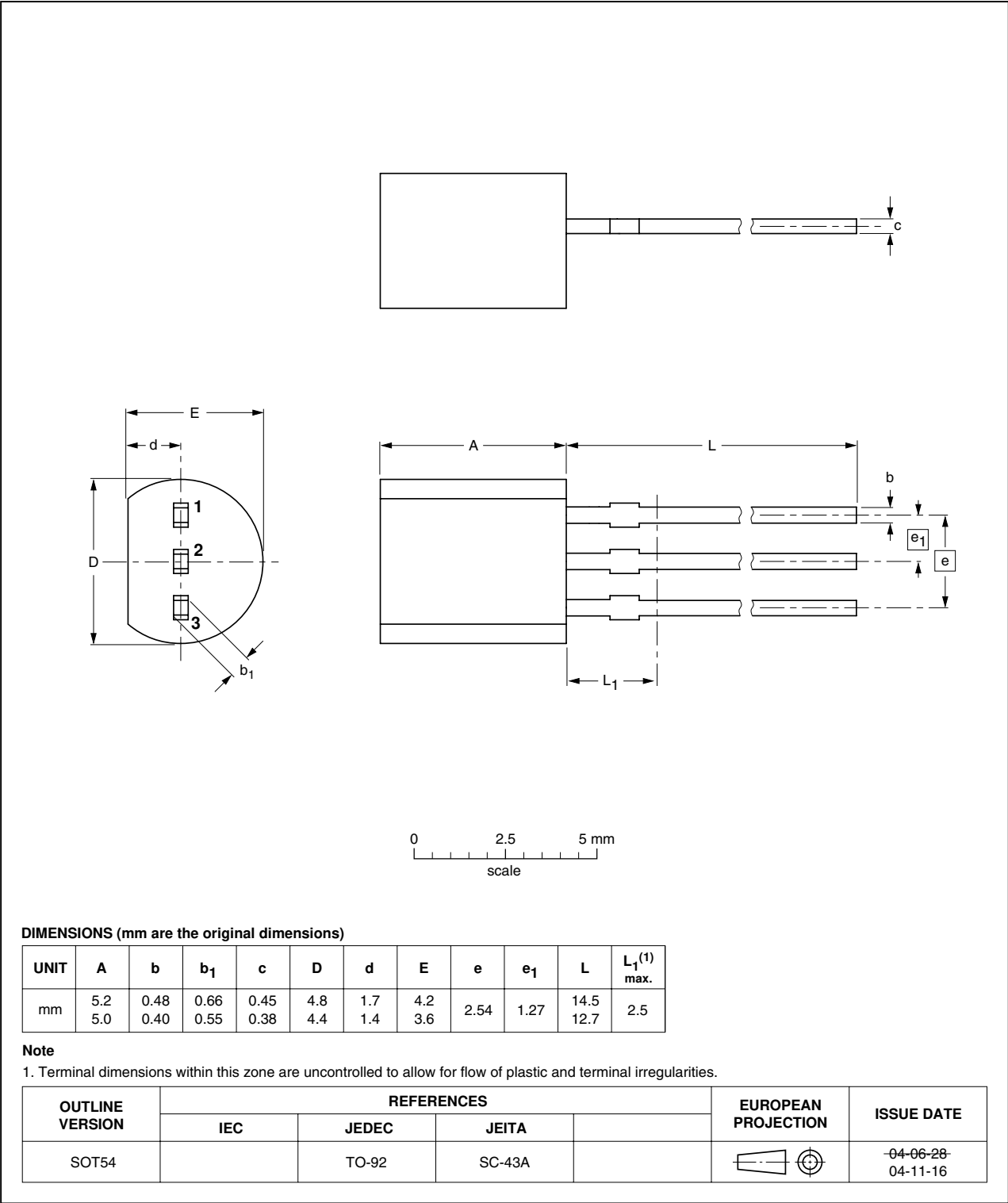


Fig 12. Package outline

9. Revision history

Table 8. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes |
|----------------|---|--------------------|---------------|-------------|
| PBSS9110S_3 | 20091122 | Product data sheet | - | PBSS9110S_2 |
| Modifications: | <ul style="list-style-type: none">• This data sheet was changed to reflect the new company name NXP Semiconductors, including new legal definitions and disclaimers. No changes were made to the technical content.• Table 2 “Discrete pinning”: amended• Figure 9 “Equivalent on-resistance as a function of collector current; typical values”: updated• Figure 10 “Equivalent on-resistance as a function of collector current; typical values”: updated• Figure 11 “Collector current as a function of collector-emitter voltage; typical values”: updated• Figure 12 “Package outline”: updated | | | |
| PBSS9110S_2 | 20040810 | Product data | - | PBSS9110S_1 |
| PBSS9110S_1 | 20040607 | Product data | - | - |

10. Legal information

10.1 Data sheet status

| Document status ^{[1][2]} | Product status ^[3] | Definition |
|-----------------------------------|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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